

PJD40P06A-AU

60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-39 A

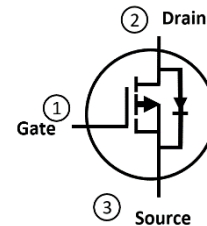
Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-20A < 27m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-10A < 37m\Omega$
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.3217 grams

TO-252AA



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-60	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^(Note 3)	$T_C=25^\circ\text{C}$	I_D	-39	A
	$T_C=100^\circ\text{C}$		-27	
Pulsed Drain Current ^(Note 1)	$T_C=25^\circ\text{C}$	I_{DM}	-83	
Power Dissipation	$T_C=25^\circ\text{C}$	P_D	81	W
	$T_C=100^\circ\text{C}$		40	
Continuous Drain Current ^(Note 4)	$T_A=25^\circ\text{C}$	I_D	-7.5	A
	$T_A=70^\circ\text{C}$		-6.2	
Power Dissipation	$T_A=25^\circ\text{C}$	P_D	3	W
	$T_A=70^\circ\text{C}$		2.1	
Single Pulse Avalanche Current ^(Note 5)		I_{AS}	-14	A
Single Pulse Avalanche Energy ^(Note 5)		E_{AS}	88	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~175	$^\circ\text{C}$
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	1.85	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	50	

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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

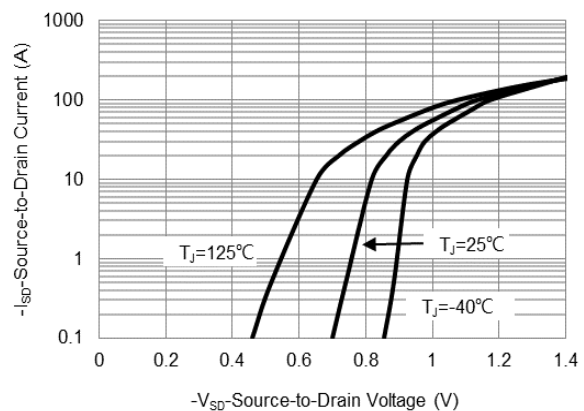
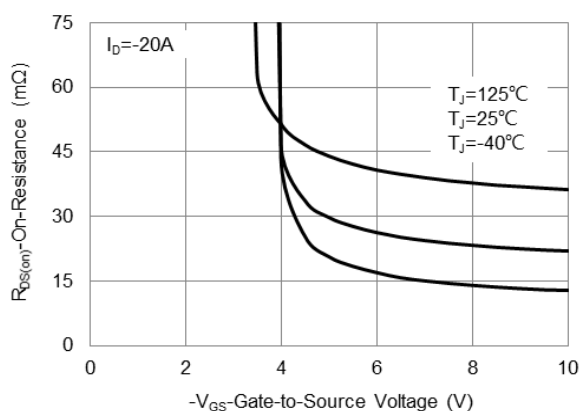
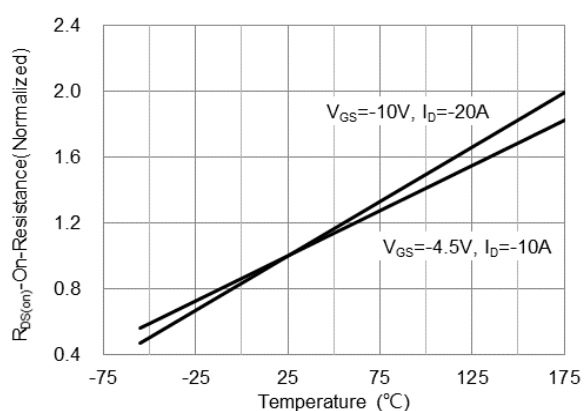
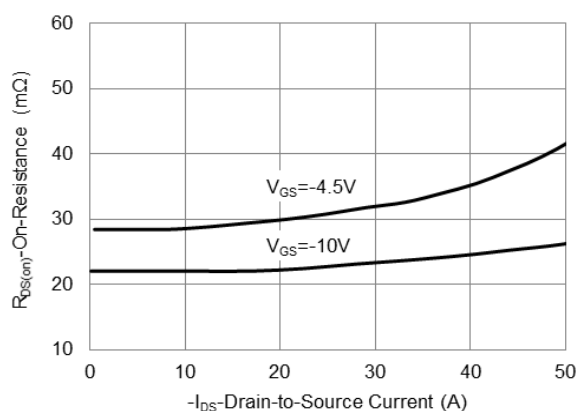
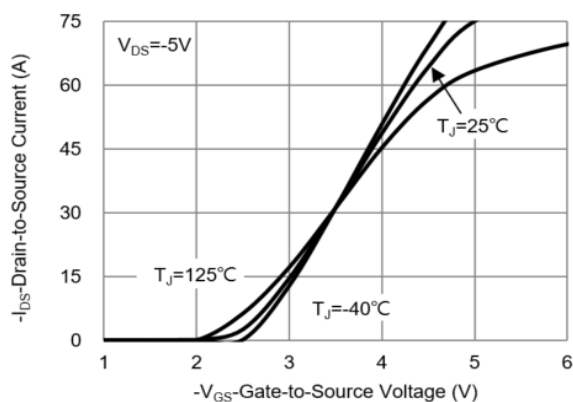
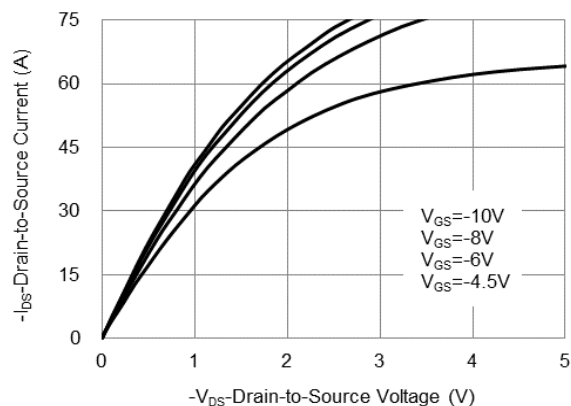
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.7	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-20A	-	21.7	27	mΩ
		V _{GS} =-4.5V, I _D =-10A	-	28.6	37	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =-30V, I _D =-20A, V _{GS} =-10V	-	44	58	nC
Gate-Source Charge	Q _{gs}		-	11	-	
Gate-Drain Charge	Q _{gd}		-	7	-	
Input Capacitance	C _{iss}	V _{DS} =-30V, V _{GS} =0V, f=1MHz	-	2530	3290	pF
Output Capacitance	C _{oss}		-	151	228	
Reverse Transfer Capacitance	C _{rss}		-	108	162	
Gate resistance	R _g	f=1MHz	-	4.8	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =-30V, I _D =-20A, V _{GS} =-10V, R _G =3Ω (Note 2)	-	7	-	ns
Turn-On Rise Time	tr		-	9	-	
Turn-Off Delay Time	td _(off)		-	41	-	
Turn-Off Fall Time	tf		-	21	-	
Drain-Source Diode						
Diode Forward Current	I _S	T _C =25° C (Package Limit)	-	-	-39	A
Pulsed Diode Forward Current	I _{SM}		-	-	-83	
Diode Forward Voltage	V _{SD}	I _S =-20A, V _{GS} =0V	-	-0.85	-1.3	V
Reverse Recovery Time	T _{rr}	V _{DD} =-30V,V _{GS} =0V	-	16	-	ns
Reverse Recovery Charge	Q _{rr}	I _S =-20A,dI _S /dt=100A/us	-	10	-	nC

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz. square pad of copper.
5. E_{AS} is calculated based on the condition of $L=1mH$, $I_{AS}=-13.3A$, $V_{DD}=-30V$, $V_{GS}=-10V$. 100% test at $L=0.5mH$, $I_{AS}=-14A$ in production.
6. Guaranteed by design, not subject to production testing.

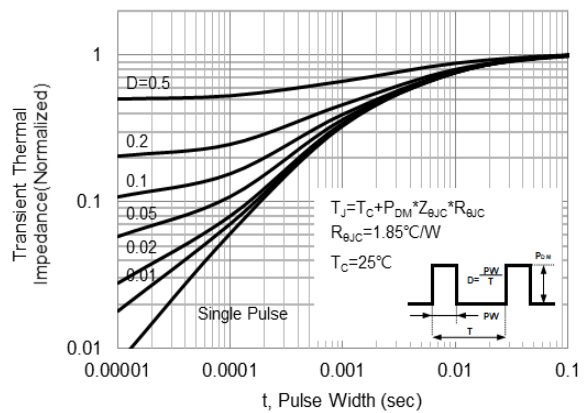
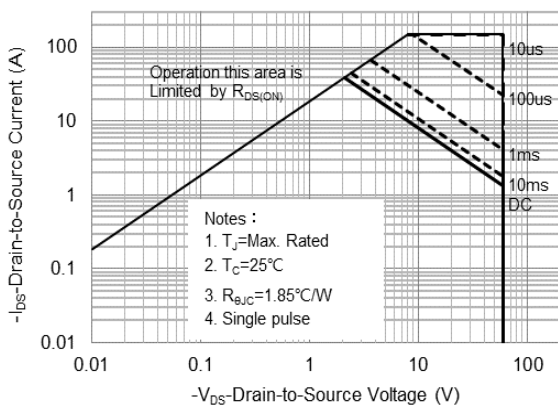
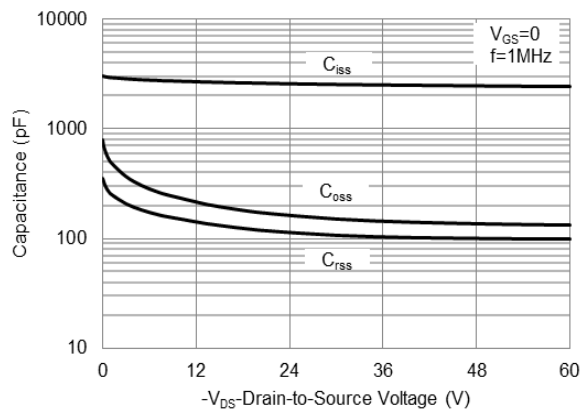
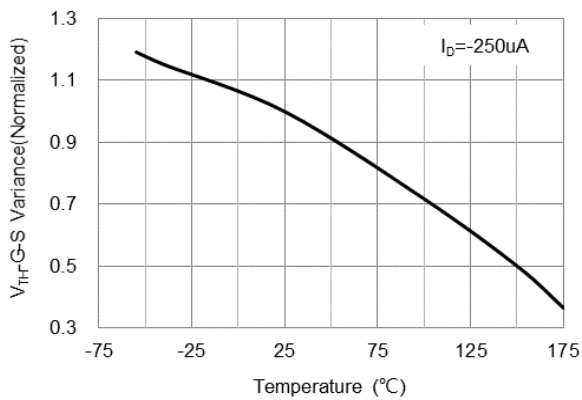
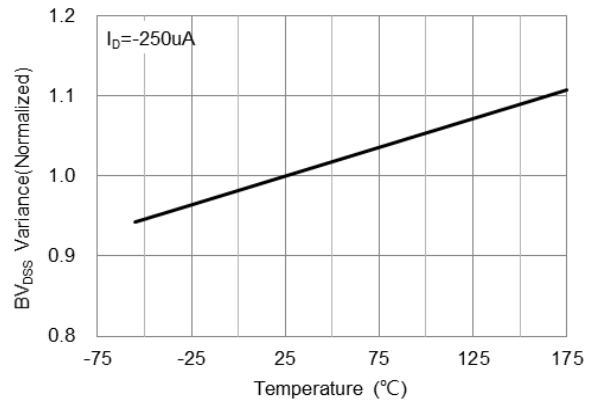
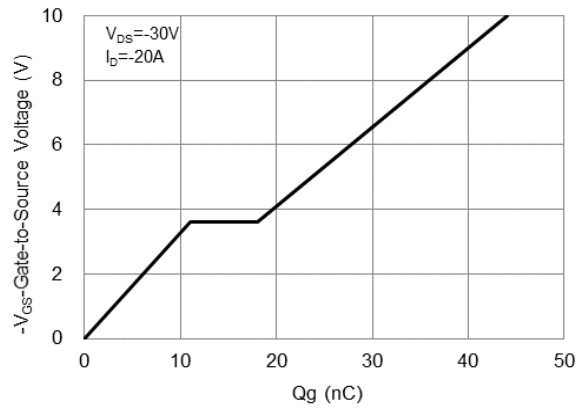
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TYPICAL CHARACTERISTIC CURVES



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TYPICAL CHARACTERISTIC CURVES

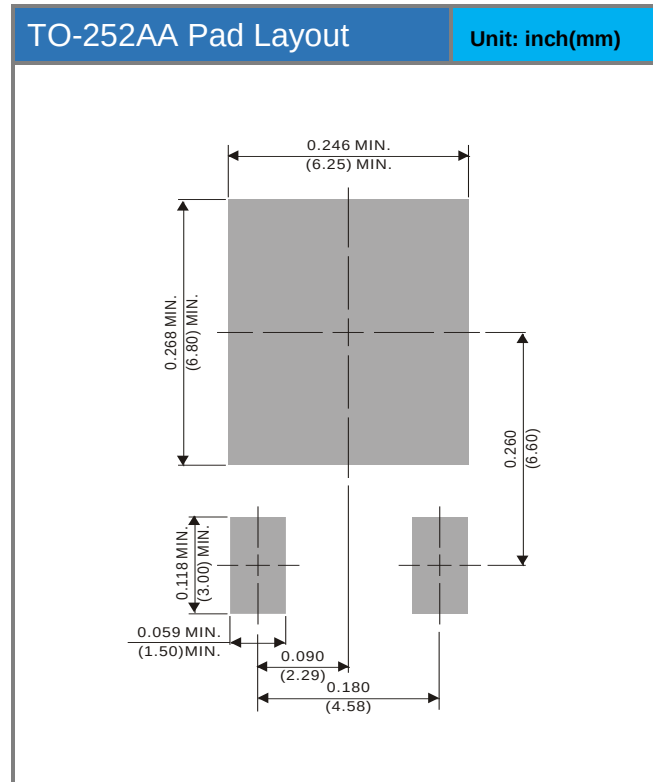
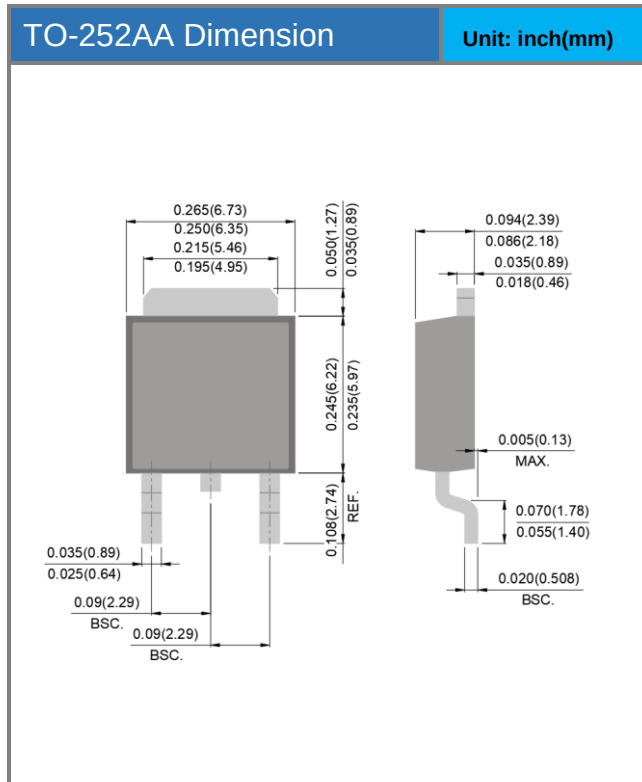


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJD40P06A-AU	TO-252AA	3K pcs / 13" reel	D40P06A

Packaging Information & Mounting Pad Layout



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